PCN Number:				20121105001 <mark>D</mark>			PCN Da	te:	06	/25/2013		
Title:   Qualification of CLARK-AT as new assembly site for affected device(s) moving from SCSAT and corresponding package change from punched RTK to sawn RGP												
Custom Contact		er	PCN_ww_ac	admin_team@list.ti.com			Phone:	+1(214)480-6037		Dep	pt:	Quality Services
Proposed 1 <sup>st</sup> Ship Dat			te:		02/19/2013	<b>Estimated Sample Availabilit</b>			t <b>y:</b>	01	/16/2013	
Change Type:												
Assembly Site					Assembly Process			$\boxtimes$	Assembly	/ Mat	eria	ls
Design					Electrical Specification			Mechanical Specification				
Test Site					Packing/Shipping/Labeling			Test Process				
Wafer Bump Site					Wafer Bump Material			Wafer Bump Process				
Wafer Fab Site					Wafer Fab Materials			Wafer Fab Process				
PCN Details												

#### **Description of Change:**

The purpose of this D version of the PCN is to clarify the last date PCN affected devices (current part numbers listed in the 'product affected' section of this document) may be ordered (6/30/13), and the last day to take delivery on those devices (9/30/13). 'New part numbers' must be used to place orders after 06/30/2013. The last delivery date of current part numbers is 09/30/2013.

Texas Instruments is pleased to announce the ongoing qualification of its CLARK-AT facility as a new assembly site for 4x4 mm, 20-pin RTK VQFN packaged device(s) currently being assembled at its SCSAT subcon facility. A package change (see package mechanical drawings) and an order number change will accompany this change. The sawn RGP package is considered backwards compatible with the punched RTK package, i.e. no PCB footprint change is necessary. Please see the tables below for further details on site and associated RoHS compliant and REACH compliant bill of material changes. Packing materials (shipping boxes, tape & reels, trays, etc.) at the additional site will be consistent with materials currently in use at that added site.

	Current	Qualification	
Assembly Site	SCSAT	CLARK-AT	
Package Designator	RTK	RGP	
Leadframe	SID#R002-2077X (NiPdAu)	4211288-0003 (NiPdAu)	
Mount Compound	SID#R008-0103X	4207123-0002	
Mold Compound	SID#R003-0302X	4208625-0005	
Bond Wire	SID#R005-0077X 25.4 µm (1 mil Au)	4072459-0500 (0.96 mil	
		Au)	

### **Device Names / Orderables**

The orderable part number will change to reflect the RGP package. Customers must convert their systems over to the new part numbers when this PCN goes into effect. The "Package Option Addendum" section in the updated datasheet as well as product information page on web will reflect these orderable device changes when they go into effect.

# Package marking:

CC1101 is used as an example below. The same marking change applies to all affected product.

Current (RTK)	Qualification ongoing (RGP)				
Topside Symbol : QFN4X4-CC ++ ! O ! Y = YEAR ! CC1101 ! M = MONTH ! YMMLLG ! M = SECONDARY SITE CODE FOR STATS ! YYWW ! LLL = ASSY LOT CODE ! G = PRIMARY SITE CODE FOR STATS +	Topside Symbol : QFN4X4-CC +				

## Package Drawings (please see datasheets for complete package Mechanical Data):





### **Reason for Change:**

Continuity of Supply

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative): Improved reliability by changing to sawn RGP package with higher package integrity. Changes to product identification resulting from this PCN:

## **Shipment Labels:**

### Current

Assembly Site	Assembly site Origin (22L)	Assembly country Origin (23L)	
SCSAT	STS	SGP	
New			
Assembly Site	Assembly site Origin (22L)	Assembly country Origin (23L)	
CLARK-AT	QAB	PHL	



Product Affected:					
Current Part number	New Part Number				
CC1100ERTKR	CC1100ERGPR				
CC1100ERTKT	CC1100ERGPT				
CC1101RTK	CC1101RGP				
CC1101RTKR	CC1101RGPR				
CC1101-LP-RTKR	CC1101-LP-RGPR				
CC110LRTKR	CC110LRGPR				
CC110LRTKT	CC110LRGPT				
CC113LRTKR	CC113LRGPR				
CC113LRTKT	CC113LRGPT				
CC115LRTKR	CC115LRGPR				
CC115LRTKT	CC115LRGPT				
HPA00409RTKR	HPA00409RGPR				
HPA00632RTKR	HPA00632RGPR				
TLMW301RTKR	TLMW301RGPR				

# **Qualification Data:**

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

<b>Qualification Schedule:</b>	Start:	2012-10-15	End:	2013-02-01	
Qualification Device Construction Details:					
Device:	See the Produ	uct Affected section of this	Qual Device1 for QBS		
	document for a list of qualified devices		CC1101RTK		
Wafer Fab:	TSMC Fab4		TSMC Fab4		
Wafer Technology:		0.18um CMOS	0.18um CMOS		
Assembly Site:		CLARK-AT	SCS-AT		
Package Type/Code:	20VQFN / RGP		20VQFN / RTK		
Package Pins:	20		20		
Mold Compound:	4208625-0005		SID#R003-0302X		
Mold Compound Supplier:	Sumitomo		Sumitomo		
Lead Frame:	4211288-0003		SID#R002-2077X		
Composition:	NiPdAu, Cu base		NiPdAu, Cu base		
Die Attach:	4207123-0002		SID#R008-0103X		
Die Attach Supplier:	Ablestik		Ablestik		
Wire Diameter:	24.3 um (0.96 mils)		24.3 um (0.96 mils)		
Moisture Level:	MSL3		MSL3		

Qualification: 🗌 Pla	n 🛛 Test Results				
Reliability Test	Conditions	Sample Size (PASS/FAIL)			
ESD HBM	Human Body Model JEDEC STD 22 A114 Per device datasheet	3 / 0 PASS (QBS)			
ESD CDM	Charged Device Model JEDEC STD 22 C101 Per device datasheet	3 / 0 PASS			
Latch-up	100mA / 1.5xVddmax JEDEC STD 78	18 / 0 PASS (QBS)			
Manufacturability	Per assembly site specification	PASS			
Pre-conditioning Level 3	24h bake @ 125°C, 192h soak @ 30°C/60%RH, 3 IR cycles 260°C + 5/-0°C SAM required JEDEC STD 22 A113	723 / 0 PASS			
Temperature Cycles air/air*	-55°C / +125°C JEDEC STD 22 A104	231 / 0 PASS			
Storage*	150°C / 600h JEDEC STD 22 A103	228 / 0 PASS			
Bias Temperature & Humidity*	130°C / 85%RH, Vmax JEDEC STD 22 A101/A110	77 / 0 PASS (QBS)			
Unbiased HAST*	110°C / 85%RH, Vmax JEDEC STD 22 A118	231 / 0 PASS			
Operating Life Test	Dynamic 140°C (480 Hrs), Vcc Max JEDEC STD 22 A108	77 / 0 PASS (QBS)			
Thermal Integrity Sequence	(level 3 @ 260C +5/-0C)	12 / 0 PASS			
Electrical characterization	Low (minimum) and high (maximum) extremes for device bias voltage and temperature.	PASS			
Notes: * Test r Qualif "QBS"	Notes: * Test requires Moisture Preconditioning   Qualification tests "pass" on zero fails for each test   "QBS" stands for Qualification by Similarity				

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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